2SD2528

Silicon NPN epitaxial planar type

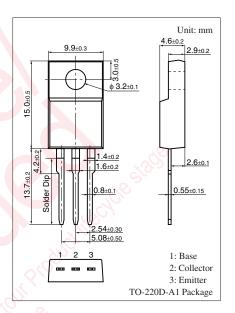
For power amplification and high-current amplification

■ Features

- ullet High forward current transfer ratio h_{FE}
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Er	V_{CBO}	80	V	
Collector-emitter voltage	V _{CEO}	60	V	
Emitter-base voltage (Collector open)		V_{EBO}	6	V
Collector current		I_{C}	5	A
Peak collector current		I_{CP}	10	A
Base current		I_{B}	1	A
Collector power	$T_C = 25^{\circ}C$	P _C	40	W
dissipation			2.0	1001
Junction temperature		T_{j}	150	°C
Storage temperature		T_{stg}	-55 to +150	°C (
			() (1111



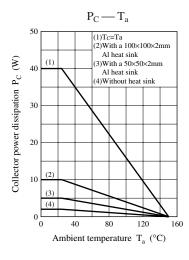
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

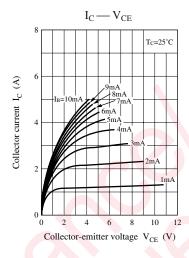
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 25 \text{ mA}, I_B = 0$	60	0.		V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 80 \text{ V}, I_{E} = 0$	~ 50°		100	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			100	μΑ
Forward current transfer ratio	h _{FE} *	$V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$	500		2000	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 4 \text{ A}, I_B = 0.1 \text{ A}$			0.3	V
Transition frequency	f_T	$V_{CE} = 12 \text{ V}, I_{C} = 0.4 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = 4 \text{ A}, I_{B1} = 0.08 \text{ A}, I_{B2} = -0.08 \text{ A}$		0.4		μs
Storage time	t _{stg}	$V_{CC} = 50 \text{ V}$		2.0		μs
Fall time	$t_{\rm f}$	<i>♦</i> //		0.6		μs

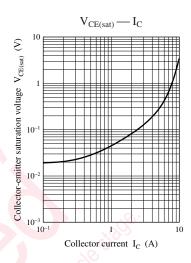
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

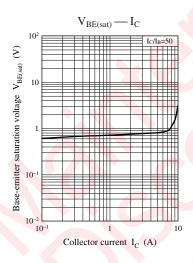
2. *: Rank classification

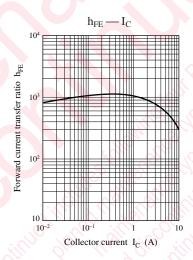
Rank	Q	Р		
$h_{\rm FE1}$	500 to 1 200	800 to 2 000		

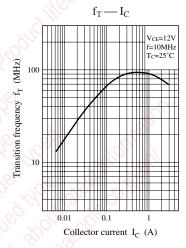


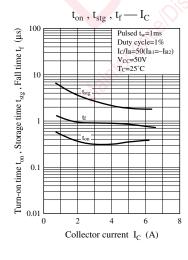


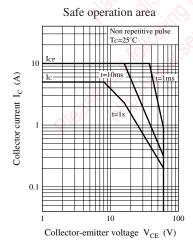












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